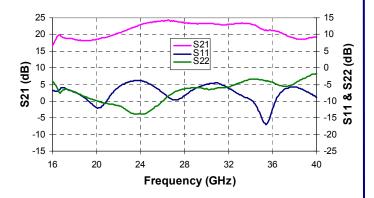


### 17 – 40 GHz MPA/Multiplier

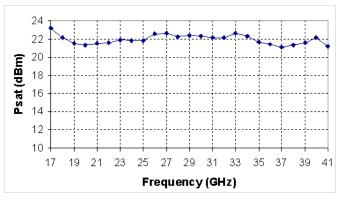


### **Measured Performance**

Bias at Vd = 5V, Id = 140mA and Vg = -0.75V (Typical)



#### Bias at Vd = 5V, Id = 140mA and Vg = -0.75V (Typical)



### **Key Features**

- RF Output Frequency Range: 17 40 GHz
- 22 dB Nominal Gain
- 22 dBm Nominal Output Maximum Power
- 2x and 3x Multiplier Function
- Bias: Vd = 5V, Id = 140mA
- Package Dimensions: 3.0 x 3.0 x 1.17 mm

### **Primary Applications**

- Point-to-Point Radio
- EW
- Instrumentation
- Frequency Multiplier

### **Product Description**

The TriQuint TGA4031-SM is an Medium Power Amplifier and Multiplier for wide band for 17 - 40GHz applications. The part is designed using TriQuint's power pHEMT production process.

The TGA4031-SM provides a nominal 22 dB small signal gain with 22 dBm output maximum power. For 2x and 3x Multiplier function, TGA4031-SM provides 15 dBm typical output power @ 9 dBm Pin.

This part is ideally suited for applications such as Point-to-Point Radio, EW, instrumentation and frequency multipliers.

Evaluation boards are available upon request.

Lead-free and RoHS compliant

Datasheet subject to change without notice.

TriQuint Semiconductor: www.triquint.com (972)994-8465 Fax (972)994-8504 Info-mmw@tqs.com





# Table IAbsolute Maximum Ratings 1/

| Symbol                                 | Parameter                   | Value    | Notes |
|--|-----------------------------|----------|-------|
| Vd-Vg                                  | Drain to Gate Voltage range | 8V       |       |
| Vd Drain Supply Voltage Range          |                             | 6 V      |       |
| Vg Gate Supply Voltage Range           |                             | -3 – 0 V |       |
| Id Drain Current 400 mA                |                             | 400 mA   |       |
| IgGate Current1.38 mA                  |                             |          |       |
| Pin Input Continuous Wave Power 20 dBm |                             |          |       |

1/ These ratings represent the maximum operable values for this device. Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device and / or affect device lifetime. These are stress ratings only, and functional operation of the device at these conditions is not implied.

### Table II Recommended Operating Conditions

| Symbol | Parameter              | Value   |
|--------|------------------------|---------|
| Vd     | Drain Voltage          | 5 V     |
| ld     | Drain Current          | 140 mA  |
| Vg     | Gate Voltage (Typical) | -0.75 V |
| Vd1    | Drain Voltage          | 1 V     |
| Vg1    | Gate Voltage           | -1.1 V  |

See bias plan on page 14 for amplifier and 2x multiplier, page 15 for 3x multiplier





Table IIIRF Characterization Table

Bias: Vd=5V, Id= 140mA, Vg = -0.75V (typical),  $T_A$ = 25 °C

| PARAMETER                                     | AMPLIFIER | 2X MULTIPLIER | <b>3x MULTIPLIER</b> | UNITS |
|---|-----------|---------------|----------------------|-------|
| RF Output Frequencies                         | 17 - 40   | 22 - 38       | 23 - 31              | GHz   |
| S21, Small Signal Gain                        | 22        | -             | -                    | dB    |
| S11, Input Return Loss                        | 10        | -             | -                    | dB    |
| S22, Output Return Loss                       | 5         | 5             | 5                    | dB    |
| Psat, Maximum Output<br>Power                 | 22        |               |                      | dBm   |
| P1dB, Output Power @ 1<br>dB Gain Compression | 18        |               |                      | dBm   |
| IMD3@ 11 dBm Pout/Tone                        | 28        |               |                      | dBc   |
| Output Power @ Pin = 9<br>dBm                 | -         | 15            | 15                   | dBm   |
| Conversion Gain                               | -         | 9             | 5                    | dB    |
| Gain Temperature<br>coefficient               | -0.04     |               |                      | dB/ºC |

- 3





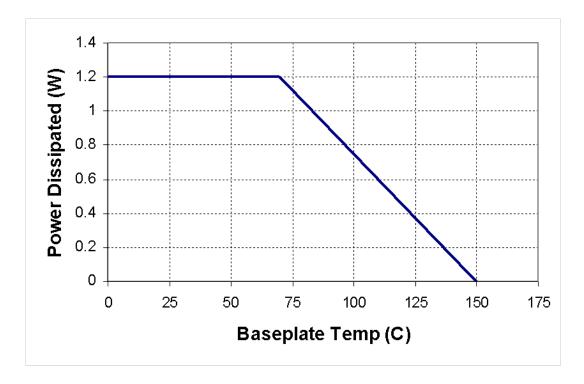
# Table IVPower Dissipation and Thermal Properties

| Parameter                 | Test Conditions                    | Value   | Notes |
|---------------------------|------------------------------------|---|-------|
| Maximum Power Dissipation | Tbaseplate = 70 °C                 | Pd = 1.2 W<br>Tchannel = 150 °C<br>Tm = 1.0E+6 Hrs        | 1/ 2/ |
| Thermal Resistance, θjc   | Vd = 5V<br>Id = 140mA<br>Pd = 0.7W | θjc = 66.7 (°C/W)<br>Tchannel = 116 °C<br>Tm = 2.4E+7 Hrs |       |
| Mounting Temperature      | 30 seconds                         | 260 °C Max  |       |
| Storage Temperature       |                                    | -65 to 150 °C   |       |

1/ For a median life, Tm, of 1E+6 hours, power dissipation is limited to

 $Pd(max) = (Tchannel °C - Tbase °C)/\theta jc.$ 

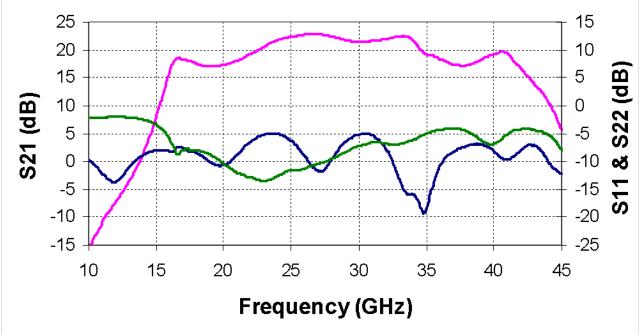
2/ Channel operating temperature will directly affect the device median time to failure (MTTF). For maximum life, it is recommended that channel temperatures be maintained at the lowest possible levels.



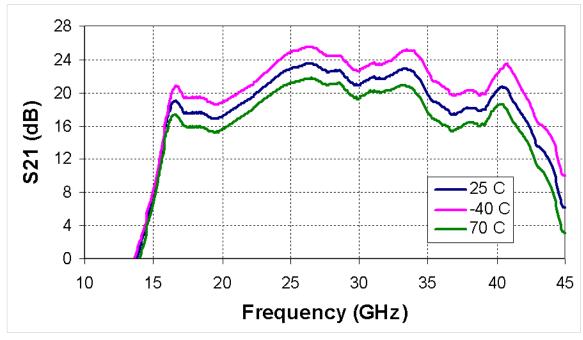


#### **Measured Data**

Bias Conditions: Vd = 5V, Idq = 140 mA, Vg = -0.75 V (Typical)



This is device s-parameter

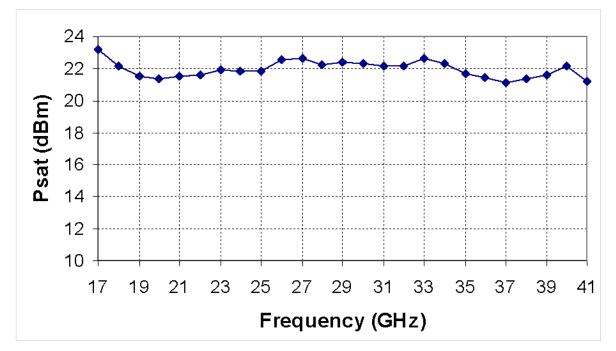


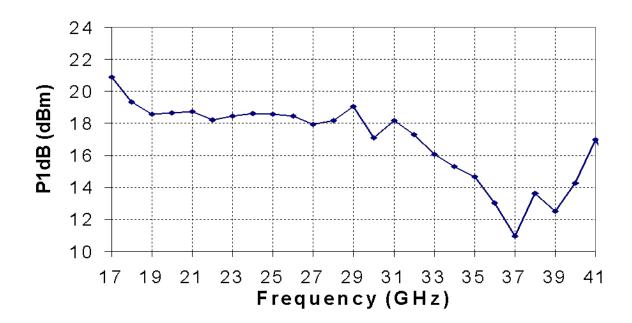
This is evaluation board s-parameter



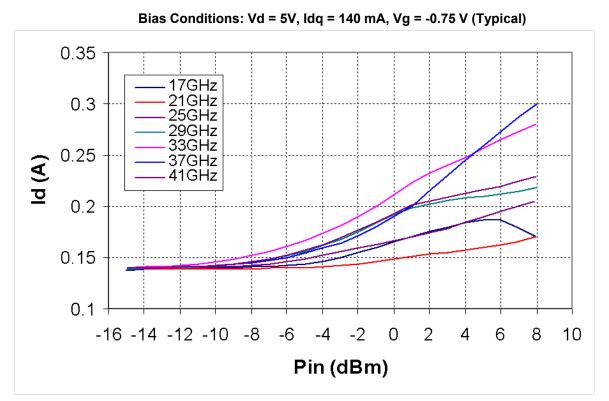
#### **Measured Data**

Bias Conditions: Vd = 5V, Idq = 140 mA, Vg = -0.75 V (Typical)

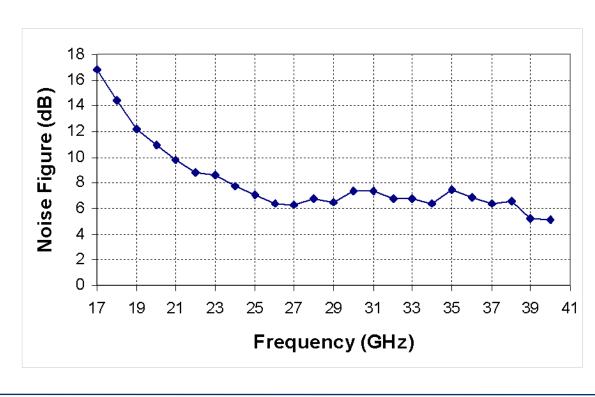










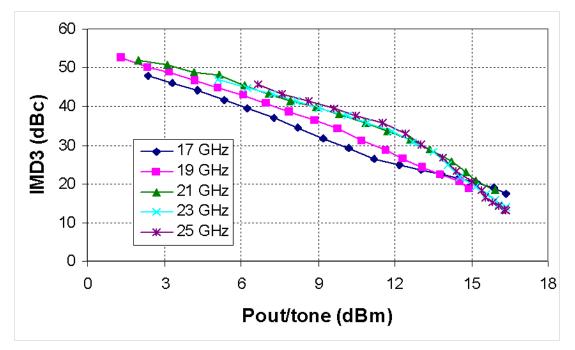


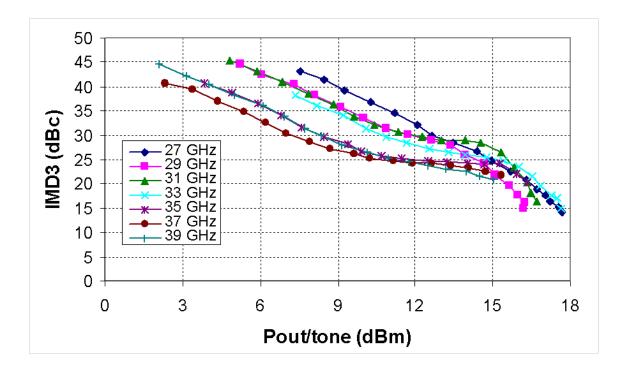
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#### **Measured Data**

Bias Conditions: Vd = 5V, Idq = 140 mA, Vg = -0.75 V (Typical)



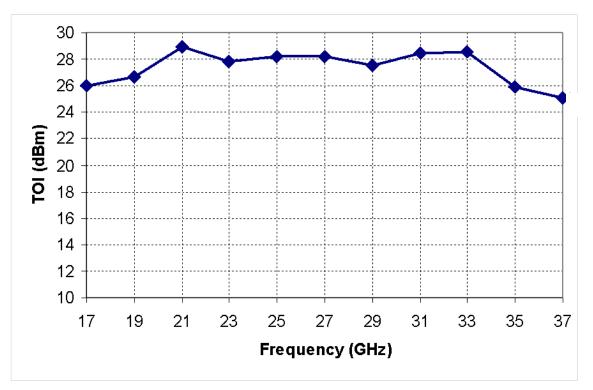




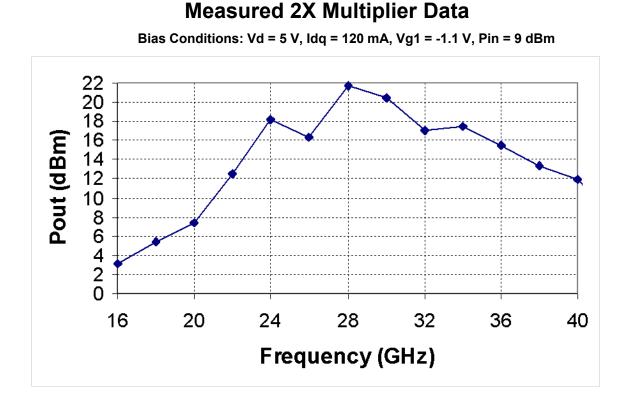


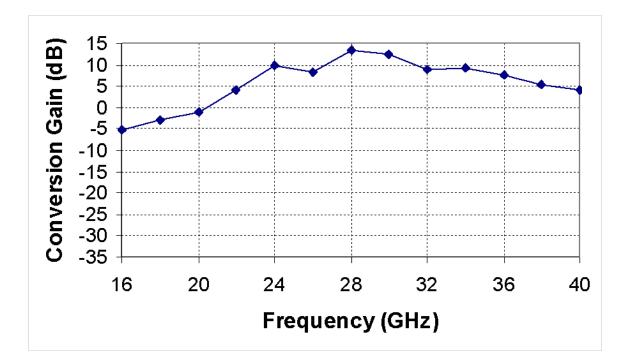


Bias Conditions: Vd = 5V, Idq = 140 mA, Vg = -0.75 V (Typical)







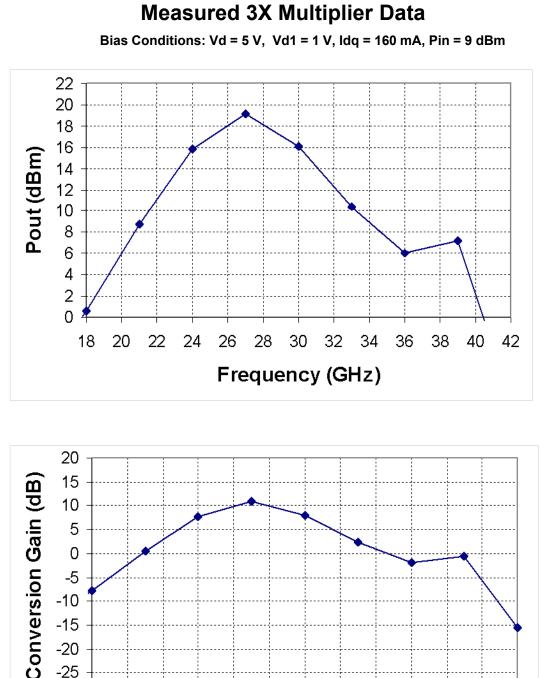




-25 -30

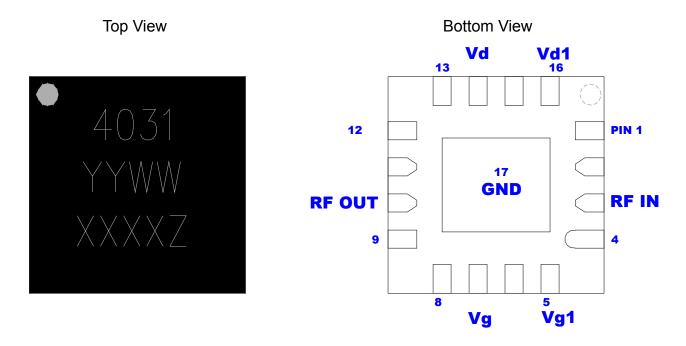
Frequency (GHz)







### **Mechanical Drawing**



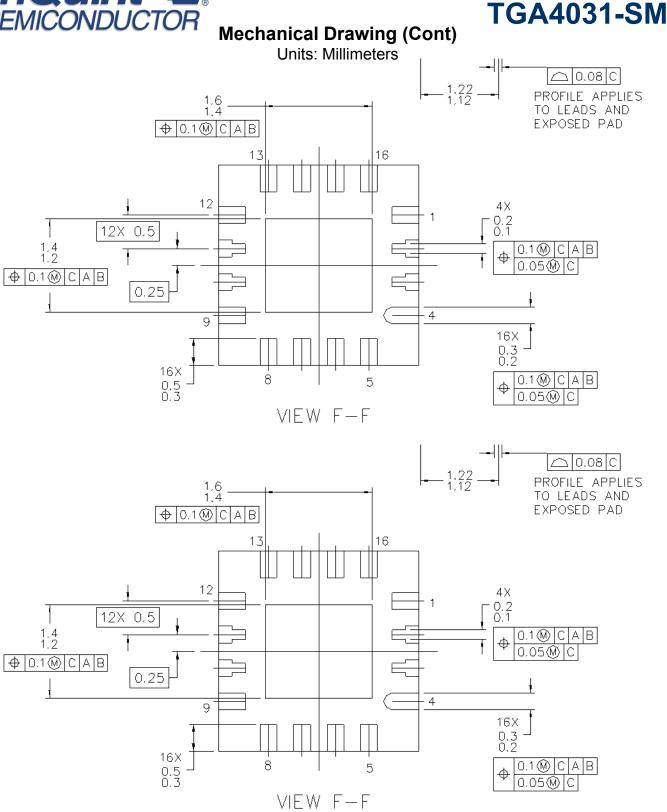
| Pin          | Symbol | Description  |  |
|--------------|--------|--|--|
| 1, 4, 9, 12  | GND    | Internal grounding; must be grounded on PCB  |  |
| 2, 11        | N/C    | lo internal connection; must be grounded on PCB  |  |
| 3            | RF IN  | nput, matched to 50 ohms   |  |
| 5            | Vg1    | Gate 1 voltage. Bias network is required; see Evaluation Board on page 14 as an example          |  |
| 6, 8, 13, 15 | GND    | No internal connection; can be grounded on PCB or left open                                      |  |
| 7            | Vg     | Gate voltage. Bias network is required; see Evaluation Board on page 14 as an example            |  |
| 10           | RF OUT | Output, matched to 50 ohms   |  |
| 14           | Vd     | Drain voltage. Bias network is required; see Evaluation Board on page 14 as an example           |  |
| 16           | Vd1    | Drain 1 voltage. Bias network is required; see Evaluation Board on page 14 as an example         |  |
| 17           | GND    | Backside Paddle. Multiple vias should be employed to minimize inductance and thermal resistance. |  |

This package is lead-free/RoHS-compliant. The package base is copper alloy and the plating material on the leads is NiPdAu. It is compatible with both lead-free (maximum 260 °C reflow temperature) and tin-lead (maximum 245 °C reflow temperature) soldering processes.

The TGA44031-SM will be marked with the "4031" designator and a lot code marked below the part designator. The "YY" represents the last two digits of the year the part was manufactured, the "WW" is the work week, and the "XXXXZ" is the lot wafer code.

GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.



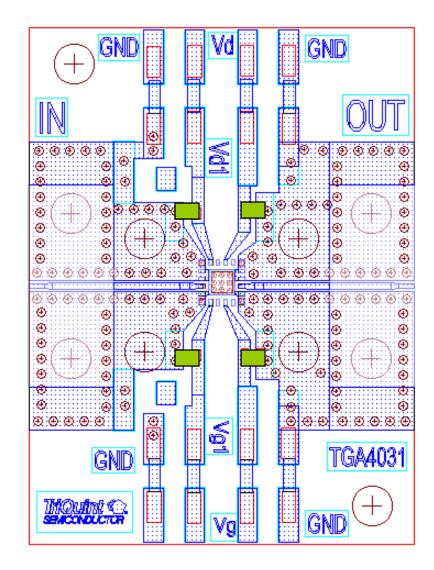


GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.





### **Evaluation Board**





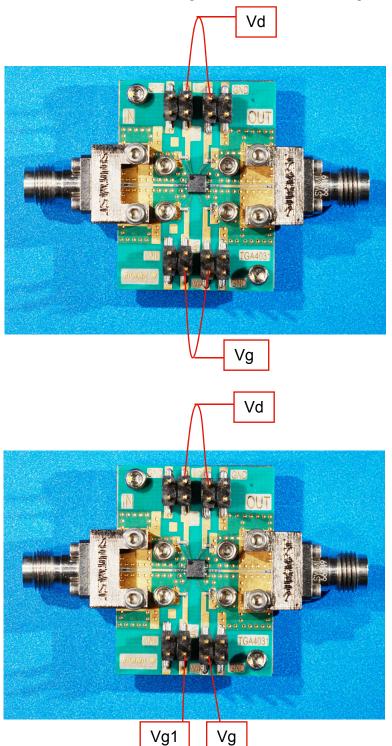
0402 0.01 uF capacitors

Board material is 8 mil ROGERS RO4003



### **Recommended Power Supply Connection Diagram**

### **Amplifier & 2X Multiplier**



#### **Bias Procedure**

Powering up:

Set Vg (starting from 0V) to -1.5V

Increase Vd (starting from 0V) to desired voltage 5V

Make Vg more positive, ending up at approx -0.75V. Id  $\sim$ 140mA.

Apply RF (max input level +20dBm).

Powering down:

Remove RF

Reduce Vd to 0V

Set Vg to -1.5V.

#### Amplifier

Set Vd = 5.0V Vary (Vg + Vg1) to achieve Id = 140mA

#### 2x Multiplier

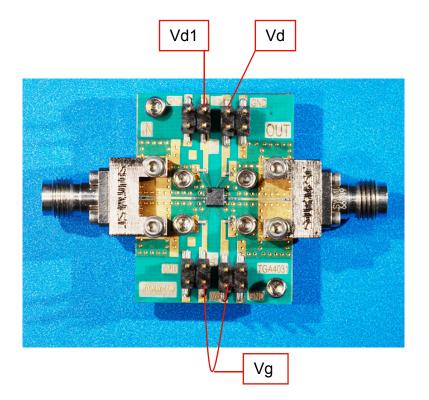
Set Vd = 5.0V Set Vg1 = -1.1V Vary Vg to achieve Id = 120mA





### **Recommended Power Supply Connection Diagram**

### **3X Multiplier**



#### **3x Multiplier**

Set Vd = 5.0V Set Vd1 = 1.0V Vary (Vg + Vg1) to achieve (Id + Id1) = 160mA



#### **Recommended Surface Mount Package Assembly**

Proper ESD precautions must be followed while handling packages.

TriQuint recommends using a conductive solder paste for attachment. Follow solder paste and reflow oven vendors' recommendations when developing a solder reflow profile. Typical solder reflow profiles are listed in the table below.

Hand soldering is not recommended. Solder paste can be applied using a stencil printer or dot placement. The volume of solder paste depends on PCB and component layout and should be well controlled to ensure consistent mechanical and electrical performance.

Solder attach process requires the use of no clean flux.

| Reflow Profile                          | SnPb                        | Pb Free                     |  |
|---|-----------------------------|-----------------------------|--|
| Ramp-up Rate                            | 3 °C/sec                    | 3 °C/sec                    |  |
| Activation Time and<br>Temperature      | 60 – 120 sec @ 140 – 160 °C | 60 – 180 sec @ 150 – 200 °C |  |
| Time above Melting Point                | 60 – 150 sec                | 60 – 150 sec                |  |
| Max Peak Temperature                    | 240 °C                      | 260 °C                      |  |
| Time within 5 °C of Peak<br>Temperature | 10 – 20 sec                 | 10 – 20 sec                 |  |
| Ramp-down Rate                          | 4 – 6 °C/sec                | 4 – 6 °C/sec                |  |

#### **Typical Solder Reflow Profiles**

### **Ordering Information**

| Part       | Package Style |  |
|------------|---------------|--|
| TGA4031-SM | 3X3 QFN       |  |